

AP2302A 20V N-Channel Enhancement Mode MOSFET

• General Description

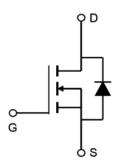
AP2302A combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(\text{ON})}$. This device is most suitable to load-switch or PWM applications.

Applications

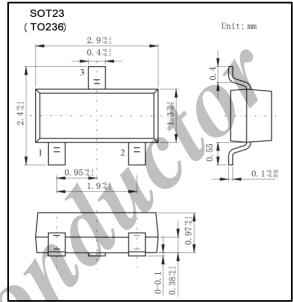
- DC/DC converter for portable devices
- Load switch

• Product Summary

$V_{ extsf{DS}}$	20V
In (at $V_{GS} = 4.5V$)	2.8A
$R_{DS(ON)}$ (at $V_{GS} = 4.5V$)	< 85mΩ
$R_{DS(ON)}$ (at $V_{GS} = 2.5V$)	< 115mΩ











• Absolute Maximum Ratings (Ta = 25°C unless noted)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V_{DS}	20	V	
Gate-Source Voltage	V_{GS}	±8	V	
Continuous Drain Current *b	I_{D} (Ta = 25°C)	2.8	A	
	$I_{\rm D}$ (Ta = 70°C)	2.2		
Pulsed Drain Current *a	I_{DM}	10		
Power Dissipation *b	P_{D} (Ta = 25°C)	1.25	W	
	P_{D} (Ta = 70°C)	0.8		
Thormal Degistance Jungtion to Ambient	$R_{\theta JA}$ *b	100	°C/W	
Thermal Resistance. Junction-to-Ambient	$R_{\theta JA}$ *c	166		
Junction Temperature	T_{J}	150	°C	
Storage Temperature Range	T_{STG}	-55 to 150	C	

Notes

- *a Pulse width limited by maximum junction temperature
- *b Surface Mounted on FR4 Board, $t \le 5s$.
- *c Surface Mounted on FR4 Board.

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• Electrical Characteristics (Ta = 25°C unless noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	V_{DSS}	$I_D=250\mu A, V_{GS}=0V$	20			V
Zero Gate Voltage Drain Current	Ţ	V_{DS} =20V, V_{GS} =0V			1	
	I_{DSS}	V_{DS} =20V, V_{GS} =0V, T_{J} =55°C			10	μA
Gate-Body leakage current	I_{GSS}	V_{DS} =0V, V_{GS} =±8V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	0.62	0.95	1.9	V
Drain-Source On-Resistance		V_{GS} =4.5V, I_{D} =3.6A		45	85	mΩ
	R _{DS(ON)}	V_{GS} =2.5V, I_{D} =3.1A		70	115	11177
Forward Transconductance *d	$\mathbf{g}_{ ext{FS}}$	V_{DS} =5V, I_D =3.6A		8		S
Input Capacitance	C_{iss}			300		
Output Capacitance	C_{oss}	V_{GS} =0V, V_{DS} =10V, f=1MHz		120		pF
Reverse Transfer Capacitance	C_{rss}			80		
Total Gate Charge	Q_{g}			4	10	
Gate Source Charge	Q_{gs}	V_{GS} =4.5V, V_{DS} =10V, I_{D} =3.6A		0.65		nC
Gate Drain Charge	Q_{gd}			1.5		
Turn-On Delay Time	$t_{D(on)}$			7	15	
Turn-On Rise Time	t_{r}	V_{GS} =4.5V, V_{DS} =10V, I_{D} =3.6A,		55	80	,,,
Turn-Off Delay Time	$t_{\mathrm{D(off)}}$	R_L =5.5 Ω , R_{GEN} =6 Ω		16	60	ns
Turn-Off Fall Time	$t_{\rm f}$			10	25	
Continuous Source Current (Diode Conduction)	Is			1.6		A
Diode Forward Voltage	V_{SD}	I_S =1.6A, V_{GS} =0V		0.76	1.2	V

Note

Ordering Information

Ordering Part Number	Package	MOQ
AP2302A	SOT23 (TO236)	3,000 pcs / reel

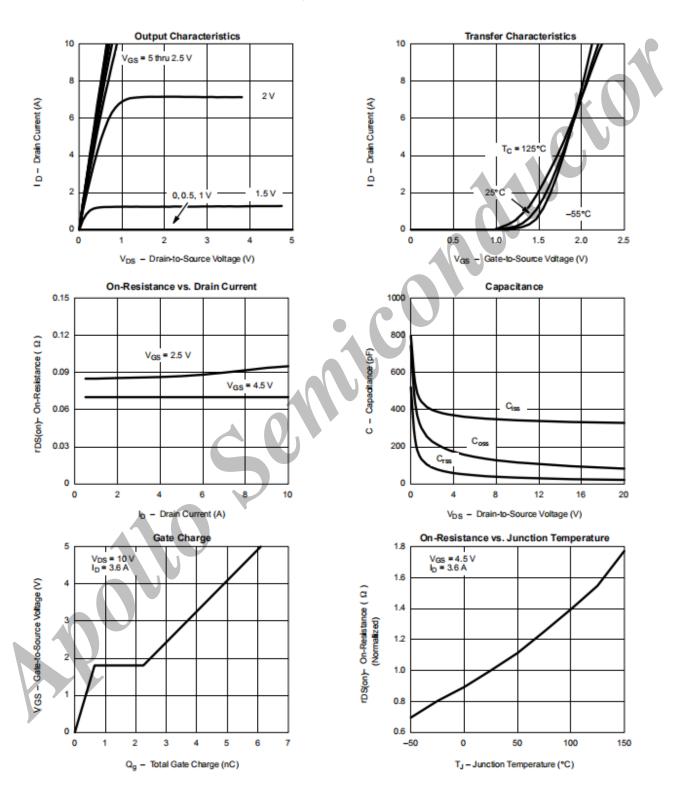
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^{*}d Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%



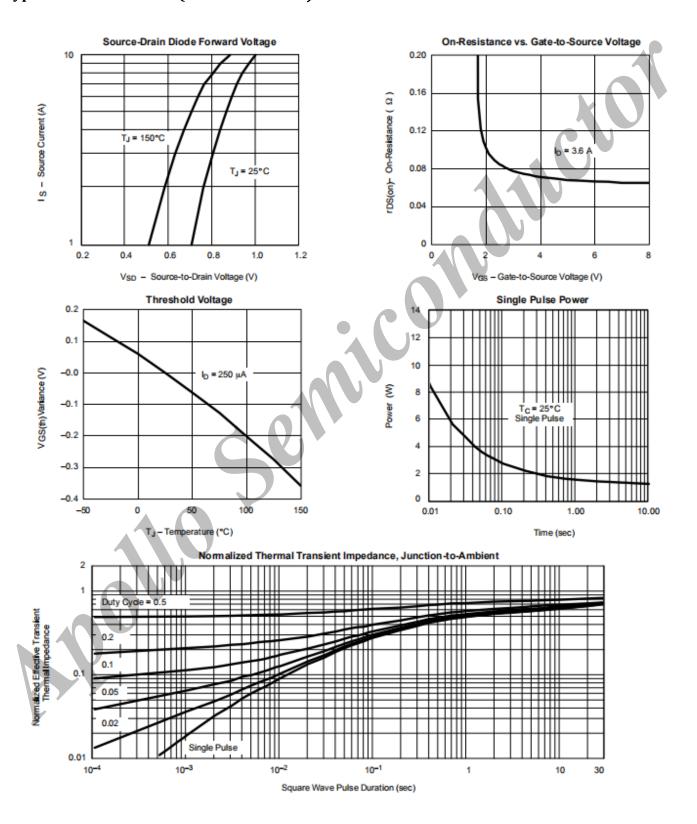


• Typical Characteristics (25°C unless noted)





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